

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	4	"4017340".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 05:40
L2	129396	(semicondcutor si silicon gaas) with wafer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 05:41
L3	200103	(multiple plurality) with (chip dice (integrated adj circuit) ic die)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 05:42
L4	3253	2 same 3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 05:42
L5	889	(polyester phenolic polimide polysulfone (polyether with ether with ketone) polyurthane epoxy (polyarylene with ether) (polyethylene with terephthalate)) and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 05:44
L6	889	(polyester phenolic polimide polysulfone (polyether with ether with ketone) polyurthane epoxy (polyarylene with ether) (polyethylene with terephthalate) (polyarylene with ether)) and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 05:46
L7	112	(sin sio2 sic teos fteos fsg osg) and 6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 05:46